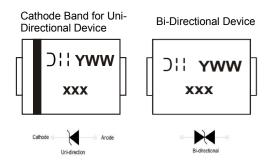


Marking Information



xx = Product Type Marking Code (See Electrical Characteristics Table) D!! = Manufacturers' Marking YWW = Date Code Marking Y = Last Digit of Year (ex: 1 for 2021) WW = Week Code (01 to 53)

Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Peak Pulse Power Dissipation (Non-Repetitive Current Pulse Derated Above T _A = +25°C) (Note 6)	P _{PK}	400	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave Superimposed on Rated Load (Notes 6, 7, 8)	I _{FSM}	40	Α
Steady State Power Dissipation @ T _L = +75°C	PM _(AV)	1.0	W
Instantaneous Forward Voltage @ I _{PP} = 35A (Notes 6, 7, 8)	V_{F}	3.5	V

Notes:

- 6. Valid provided that terminals are kept at ambient temperature.
- 7. Measured with 8.3ms single half sine-wave. Duty cycle = 4 pulses per minute maximum.
- 8. Unidirectional units only.

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Operating Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +175	°C

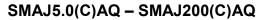


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

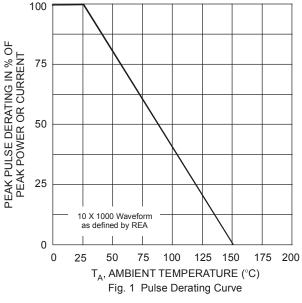
Part Number Add C For Bidirectional	Reverse Standoff Voltage	Vol	down tage @ I _T e 10)	Test Current	Max. Reverse Leakage @ V _{RWM} (Note 12)	Max. Clamping Voltage @ I _{PP} (Note 11)	Max. Peak Pulse Current	Markin	g Code
(Note 9)	V _{RWM} (V)	Min (V)	Max (V)	I _T (mA)	I _R (μA)	V _C (V)	I _{PP} (A)	BI-	UNI-
SMAJ5.0(C)AQ	5.0	6.40	7.25	10	800	9.2	43.5	TE	HE
SMAJ7.5(C)AQ	7.5	8.33	9.21	1.0	100	12.9	31.0	TP	HP
SMAJ8.5(C)AQ	8.5	9.44	10.4	1.0	10	14.4	27.7	TT	HT
SMAJ10(C)AQ	10	11.1	12.3	1.0	5.0	17.0	23.5	TX	HX
SMAJ12(C)AQ	12	13.3	14.7	1.0	5.0	19.9	20.1	UE	ΙE
SMAJ13(C)AQ	13	14.4	15.9	1.0	5.0	21.5	18.6	UG	IG
SMAJ14(C)AQ	14	15.6	17.2	1.0	5.0	23.2	17.2	UK	IK
SMAJ15(C)AQ	15	16.7	18.5	1.0	5.0	24.4	16.4	UM	IM
SMAJ16(C)AQ	16	17.8	19.7	1.0	5.0	26.0	15.3	UP	ΙP
SMAJ17(C)AQ	17	18.9	20.9	1.0	5.0	27.6	14.5	UR	IR
SMAJ18(C)AQ	18	20.0	22.1	1.0	5.0	29.2	13.7	UT	IT
SMAJ20(C)AQ	20	22.2	24.5	1.0	5.0	32.4	12.3	UV	IV
SMAJ22(C)AQ	22	24.4	26.9	1.0	5.0	35.5	11.2	UX	IX
SMAJ24(C)AQ	24	26.7	29.5	1.0	5.0	38.9	10.3	UZ	ΙZ
SMAJ26(C)AQ	26	28.9	31.9	1.0	5.0	42.1	9.5	VE	JE
SMAJ28(C)AQ	28	31.1	34.4	1.0	5.0	45.4	8.8	VG	JG
SMAJ30(C)AQ	30	33.3	36.8	1.0	5.0	48.4	8.3	VK	JK
SMAJ33(C)AQ	33	36.7	40.6	1.0	5.0	53.3	7.5	VM	JM
SMAJ36(C)AQ	36	40.0	44.2	1.0	5.0	58.1	6.9	VP	JP
SMAJ40(C)AQ	40	44.4	49.1	1.0	5.0	64.5	6.2	VR	JR
SMAJ43(C)AQ	43	47.8	52.8	1.0	5.0	69.4	5.7	VT	JT
SMAJ48(C)AQ	48	53.3	58.9	1.0	5.0	77.4	5.2	VX	JX
SMAJ51(C)AQ	51	56.7	62.7	1.0	5.0	82.4	4.9	VZ	JZ
SMAJ58(C)AQ	58	64.4	71.2	1.0	5.0	93.6	4.3	WG	RG
SMAJ60(C)AQ	60	66.7	73.7	1.0	5.0	96.8	4.1	WK	RK
SMAJ70(C)AQ	70	77.8	86.0	1.0	5.0	113	3.5	WP	RP
SMAJ78(C)AQ	78	86.7	95.8	1.0	5.0	126	3.2	WT	RT
SMAJ100(C)AQ	100	111	123	1.0	5.0	162	2.5	WZ	RZ
SMAJ170(C)AQ	170	189	209	1.0	5.0	275	1.4	XR	SR
SMAJ200(C)AQ	200	224	248	1.0	1.0	324	1.2	ΥT	ST

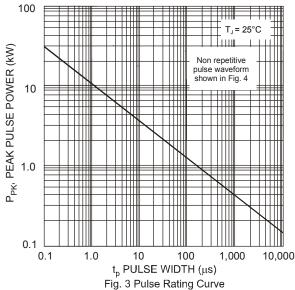
Notes:

^{9.} Suffix C denotes bidirectional device.
10. V_{BR} measured with I_T current pulse = 10ms to 15ms.
11. Per 10 × 1000 μ s waveform. See Figure 4.
12. For bidirectional devices having V_{RWM} of 10V and under, the I_R is doubled.









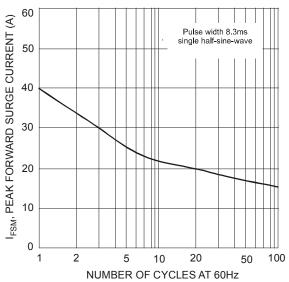


Fig. 5 Maximum Non-Repetitive Surge Current

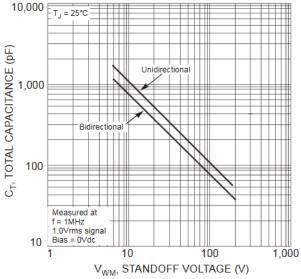
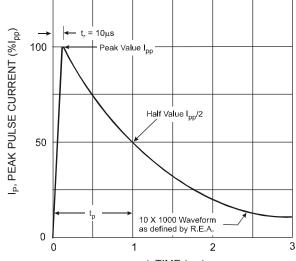


Fig. 2 Typical Total Capacitance



t, TIME (ms) Fig. 4 Pulse Waveform

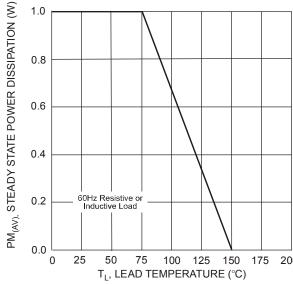


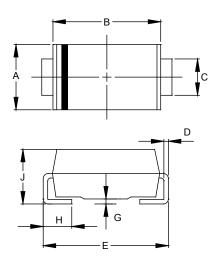
Fig. 6 Steady State Power Derating Curve



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SMA

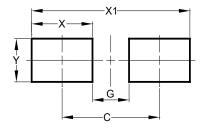


SMA					
Dim	Min	Max			
Α	2.29	2.92			
В	4.00	4.60			
С	1.27	1.63			
D	0.15	0.31			
Е	4.80	5.59			
G	0.05	0.20			
Н	0.76	1.52			
J	1.96	2.40			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SMA



Dimensions	Value		
Dillielisions	(in mm)		
С	4.00		
G	1.50		
Х	2.50		
X1	6.50		
Υ	1.70		



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